

PNP Silicon General Purpose High Voltage Transistor

MSB92WT1G, MSB92AWT1G

This PNP Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

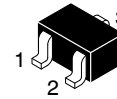
Symbol	Rating	Value	Unit
$V_{(BR)CBO}$	Collector-Base Voltage	-300	Vdc
$V_{(BR)CEO}$	Collector-Emitter Voltage	-300	Vdc
$V_{(BR)EBO}$	Emitter-Base Voltage	-5.0	Vdc
I_C	Collector Current – Continuous	500	mA
ESD	Electrostatic Discharge	MBM > 16,000, MM > 2,000	V

THERMAL CHARACTERISTICS

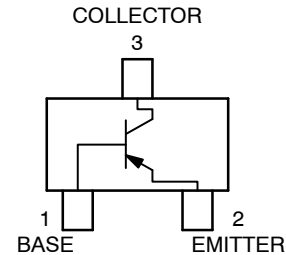
Symbol	Rating	Max	Unit
P_D	Power Dissipation (Note 1)	150	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

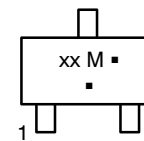
- Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



SC-70 (SOT-323)
CASE 419
STYLE 3



MARKING DIAGRAM



- xx = Device Code
 x = 2D or D2
 M = Date Code*
 ■ = Pb-Free Package

(Note: Microdot may be in either location)
 *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MSB92WT1G	SC-70/ SOT-323 (Pb-Free)	3,000/Tape & Reel
MSB92AWT1G	SC-70/ SOT-323 (Pb-Free)	3,000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

MSB92WT1G, MSB92AWT1G

ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Min	Max	Unit
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ($I_C = -1.0 \text{ mAdc}$, $I_B = 0$)	-300	-	Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C = -100 \text{ } \mu\text{Adc}$, $I_E = 0$)	-300	-	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E = -100 \text{ } \mu\text{Adc}$, $I_B = 0$)	-5.0	-	Vdc
I_{CBO}	Collector-Base Cutoff Current ($V_{CB} = -200 \text{ Vdc}$, $I_E = 0$)	-	-0.25	μA
I_{EBO}	Emitter-Base Cutoff Current ($V_{EB} = -3.0 \text{ Vdc}$, $I_B = 0$)	-	-0.1	μA
h_{FE1} h_{FE1} h_{FE2} h_{FE3}	DC Current Gain (Note 2) MSB92WT1: ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$) MSB92AWT1: ($V_{CE} = -10 \text{ Vdc}$, $I_C = -1.0 \text{ mAdc}$) ($V_{CE} = -10 \text{ Vdc}$, $I_C = -10 \text{ mAdc}$) ($V_{CE} = -10 \text{ Vdc}$, $I_C = -30 \text{ mAdc}$)	25 120 40 25	- 200 - -	-
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage (Note 2) ($I_C = -20 \text{ mAdc}$, $I_B = -2.0 \text{ mAdc}$)	-	-0.5	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C = -20 \text{ mAdc}$, $I_B = -2.0 \text{ mAdc}$)	-	-0.9	Vdc

SMALL SIGNAL CHARACTERISTICS

f_T	Current – Gain – Bandwidth Product ($I_C = -10 \text{ mAdc}$, $V_{CE} = -20 \text{ Vdc}$, $f = 20 \text{ MHz}$)	50	-	MHz
C_{cb}	Collector-Base Capacitance ($V_{CB} = -20 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)	-	6.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width $\leq 300 \text{ } \mu\text{s}$, D.C. $\leq 2\%$.

MSB92WT1G, MSB92AWT1G

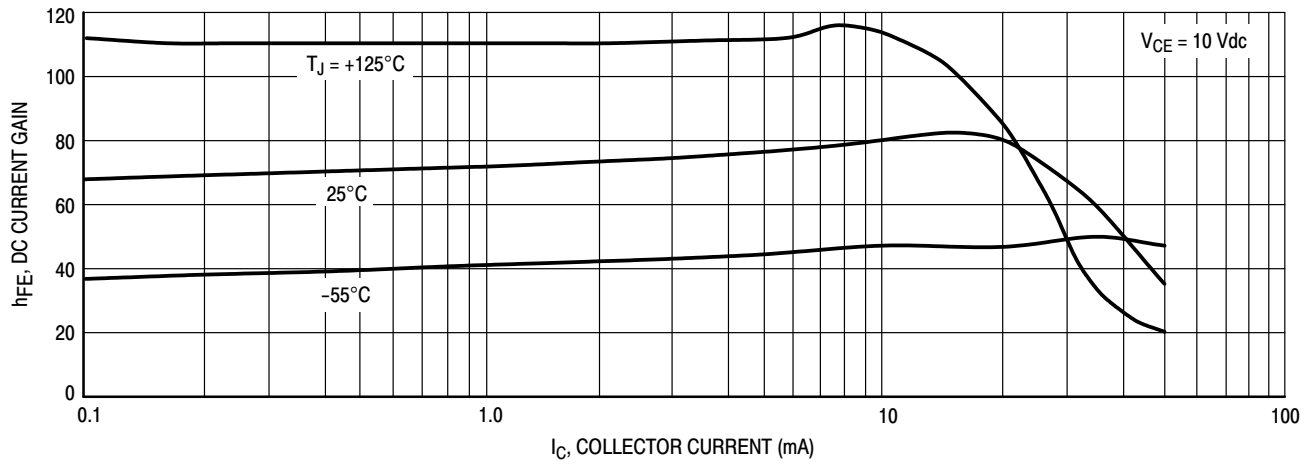


Figure 1. DC Current Gain

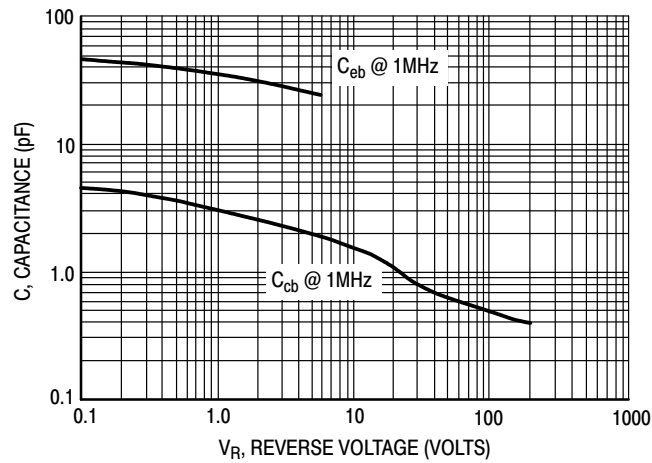


Figure 2. Capacitance

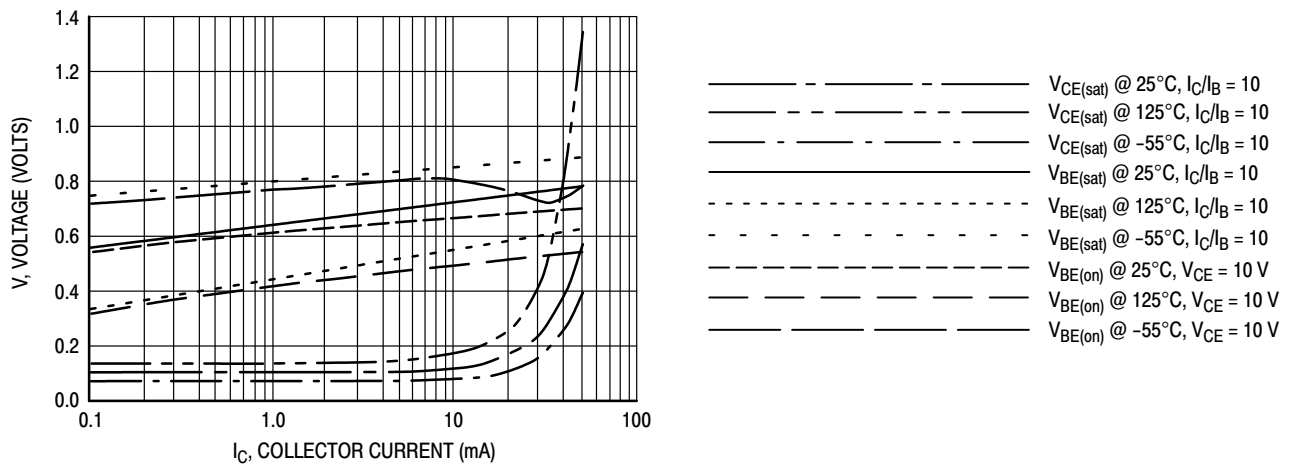
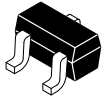


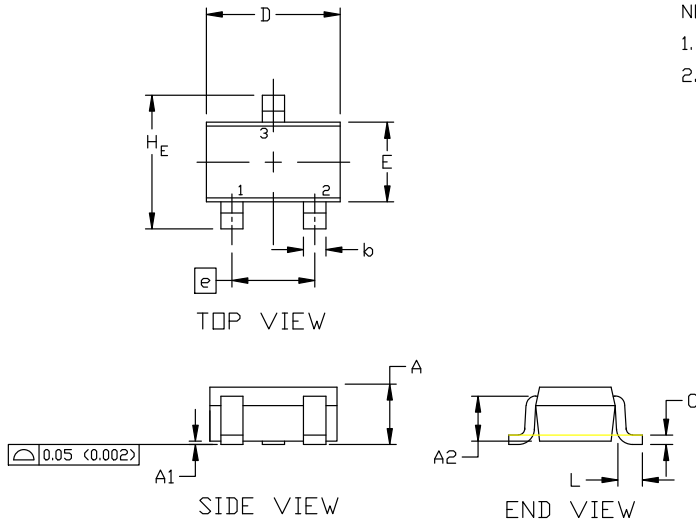
Figure 3. "ON" Voltages



SCALE 4:1

SC-70 (SOT-323)
CASE 419
ISSUE R

DATE 11 OCT 2022

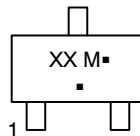


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH

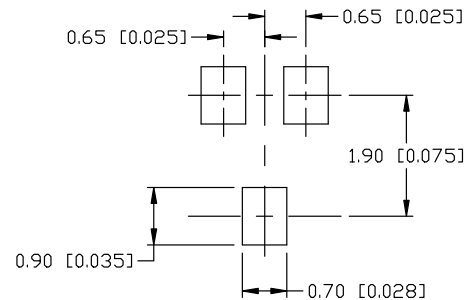
DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
H _E	2.00	2.10	2.40	0.079	0.083	0.095

GENERIC
MARKING DIAGRAM



XX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1:
CANCELLED

STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 6:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 7:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 8:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. CATHODE-ANODE

STYLE 10:
PIN 1. CATHODE
2. ANODE
3. ANODE-CATHODE

STYLE 11:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

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